

#### SSC8131GS6

#### **P-Channel Enhancement Mode MOSFET**

#### > Features

VDS	VGS	RDSON Typ.	ID
		45mR@-10V	
-30V	±12V	52mR@-4V5	-4A
		63mR@-2V5	

# > Description

This device is particularly suited for low voltage application such as portable equipment, power management and other battery powered circuits, and low in-line power dissipation are needed in a very small outline surface mount package. Excellent thermal and electrical capabilities.

# Applications

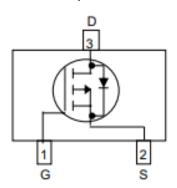
- Load Switch
- Portable Devices
- DCDC conversion

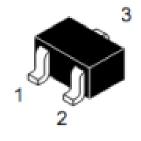
#### > Ordering Information

Device	Package	Shipping	
SSC8131GS6	SOT23	3000/Reel	

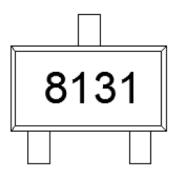
# Pin configuration

Top view





SOT23



Marking



# ➤ **Absolute Maximum Ratings**(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Ratings	Unit	
$V_{DSS}$	Drain-to-Source Voltage	-30	V	
V <sub>GSS</sub>	Gate-to-Source Voltage	±12	V	
I <sub>D</sub>	Continuous Drain Current <sup>a</sup>	-4	Α	
I <sub>DM</sub>	Pulsed Drain Current <sup>b</sup>	-15	Α	
P <sub>D</sub>	Power Dissipation <sup>c</sup>	1.35	W	
P <sub>DSM</sub>	Power Dissipation <sup>a</sup>	Power Dissipation <sup>a</sup> 0.8		
TJ	Operation junction temperature	-55 to 150	°C	
T <sub>STG</sub>	Storage temperature range -55 to 150		°C	

# ➤ Thermal Resistance Ratings(T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Parameter	Typical	Maximum	Unit
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance <sup>a</sup>		160	°C/W
R <sub>eJC</sub>	R <sub>0JC</sub> Junction-to-Case Thermal Resistance		95	C/ VV

#### Note:

- a. The value of  $R_{\theta JA}$  is measured with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz.copper,in a still air environment with  $T_A$ =25°C. The value in any given application depends on the user is specific board design. The current rating is based on the t  $\leq$  10s thermal resistance rating.
- b. Repetitive rating, pulse width limited by junction temperature.
- c. The power dissipation  $P_D$  is based on  $T_{J(MAX)}$ =150°C, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heat sinking is used.

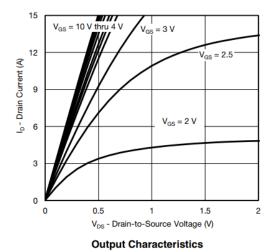


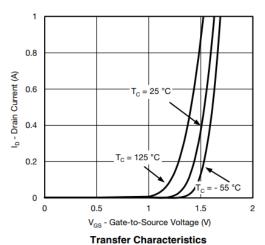
# $\blacktriangleright$ **Electronics Characteristics**(T<sub>A</sub>=25 $^{\circ}$ C unless otherwise noted)

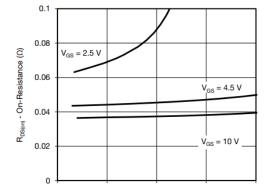
Symbol	Parameter	Test Conditions	Min	Тур.	Max	Unit
V <sub>(BR)DSS</sub>	Drain-Source	VGS=0V , ID=-250uA	-30			V
	Breakdown Voltage	7 00 07 , 15 200a/ t	00			•
V <sub>GS (th)</sub>	Gate Threshold	VDS=VGS , ID=-250uA	-0.6	-0.7	-1.1	V
	Voltage		-0.0	0.7	-1.1	v
	Drain-Source On-	VGS=-10V , ID=-4A		45	58	mR
R <sub>DS(on)</sub>	Resistance	VGS=-4.5V , ID=-2A		52	61	
	resistance	VGS=-2.5V , ID=-1A		63	71	
I <sub>DSS</sub>	Zero Gate Voltage	VDS=-30V , VGS=0V			-1	uA
	Drain Current				u, t	
I <sub>GSS</sub>	Gate-Source leak	VGS=±12V , VDS=0V			±100	nA
1633	current					
G <sub>FS</sub>	Transconductance	VDS=-5V , ID=-3A		10		S
$V_{SD}$	Forward Voltage	VGS=0V , IS=-1A		-0.7	-1.3	V
Ciss	Input Capacitance			600		
Coss	Output Capacitance	VDS=-15V , VGS=0V , f=1MHz		85		pF
Crss	Reverse Transfer		66			
	Capacitance			00		
$T_{D(ON)}$	Turn-on delay time	VGS=-6V, VGEN=-4.5V, RL=6R, RG=6R ,ID=-1.0A		13		
Tr	Rise time			18		ns
T <sub>D(OFF)</sub>	Turn-off delay time			40		113
Tf	Fall time			8		



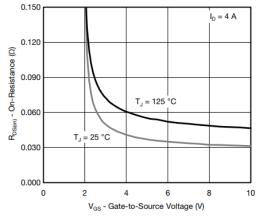
# **Typical Characteristics**(T<sub>A</sub>=25 °C unless otherwise noted)







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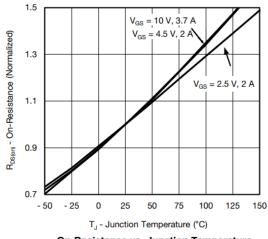
I<sub>D</sub> - Drain Current (A) On-Resistance vs. Drain Current

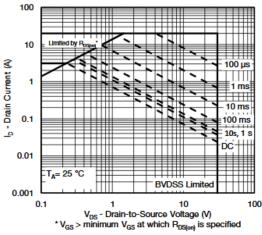
10

15

20

On-Resistance vs. Gate-to-Source Voltage



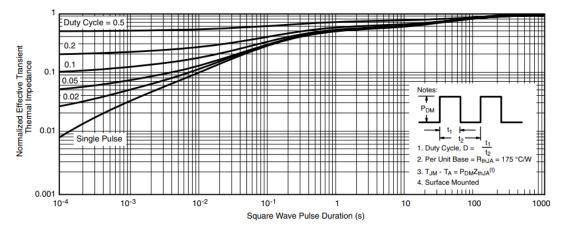


On-Resistance vs. Junction Temperature

Safe Operating Area, Junction-to-Ambient

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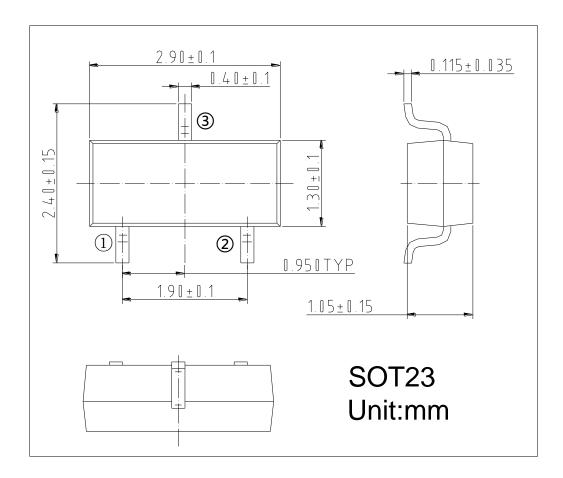




Normalized Thermal Transient Impedance, Junction-to-Ambient



#### Package Information



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